Designing Vertical Processors in Monolithic 3D

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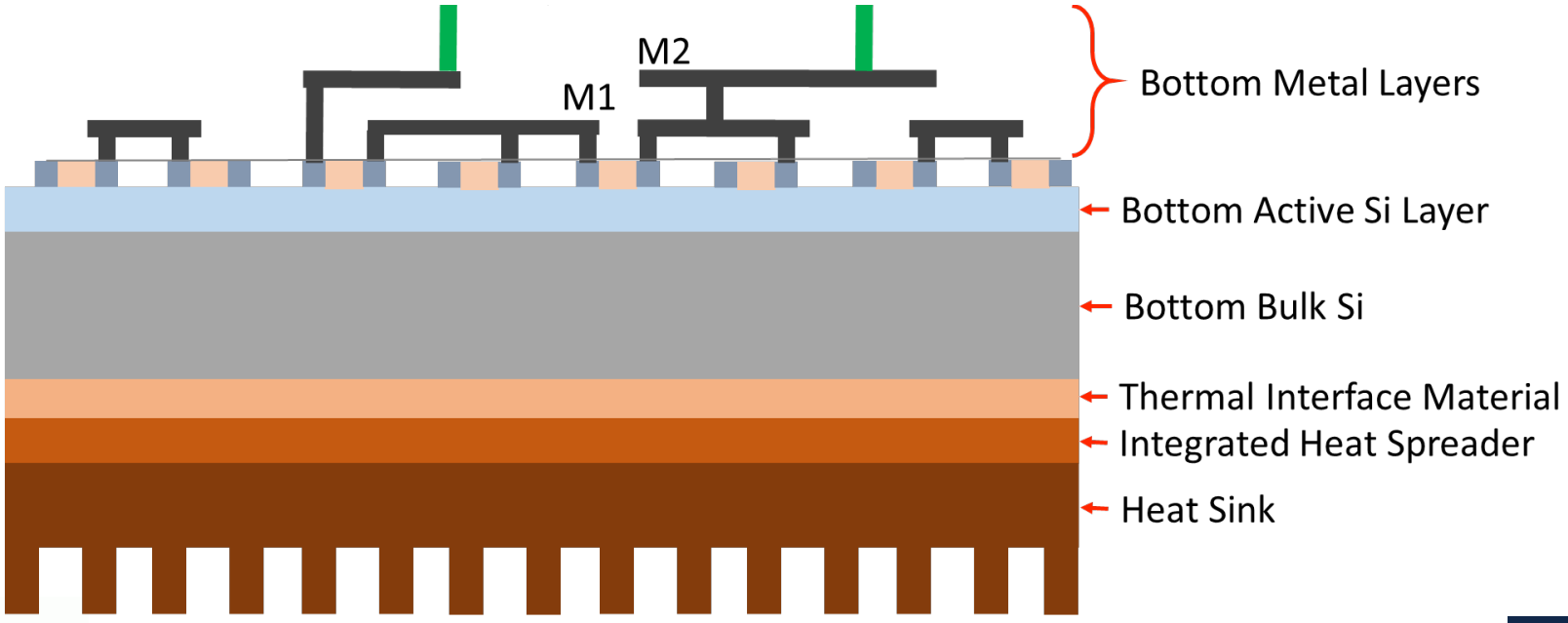
What is Monolithic 3D (M3D) ?

- Fabrication method that sequentially grows one or more Si layers on top of a base layer
  - As opposed to TSV based 3D stacking (TSV3D), that bonds pre-fabricated dies together



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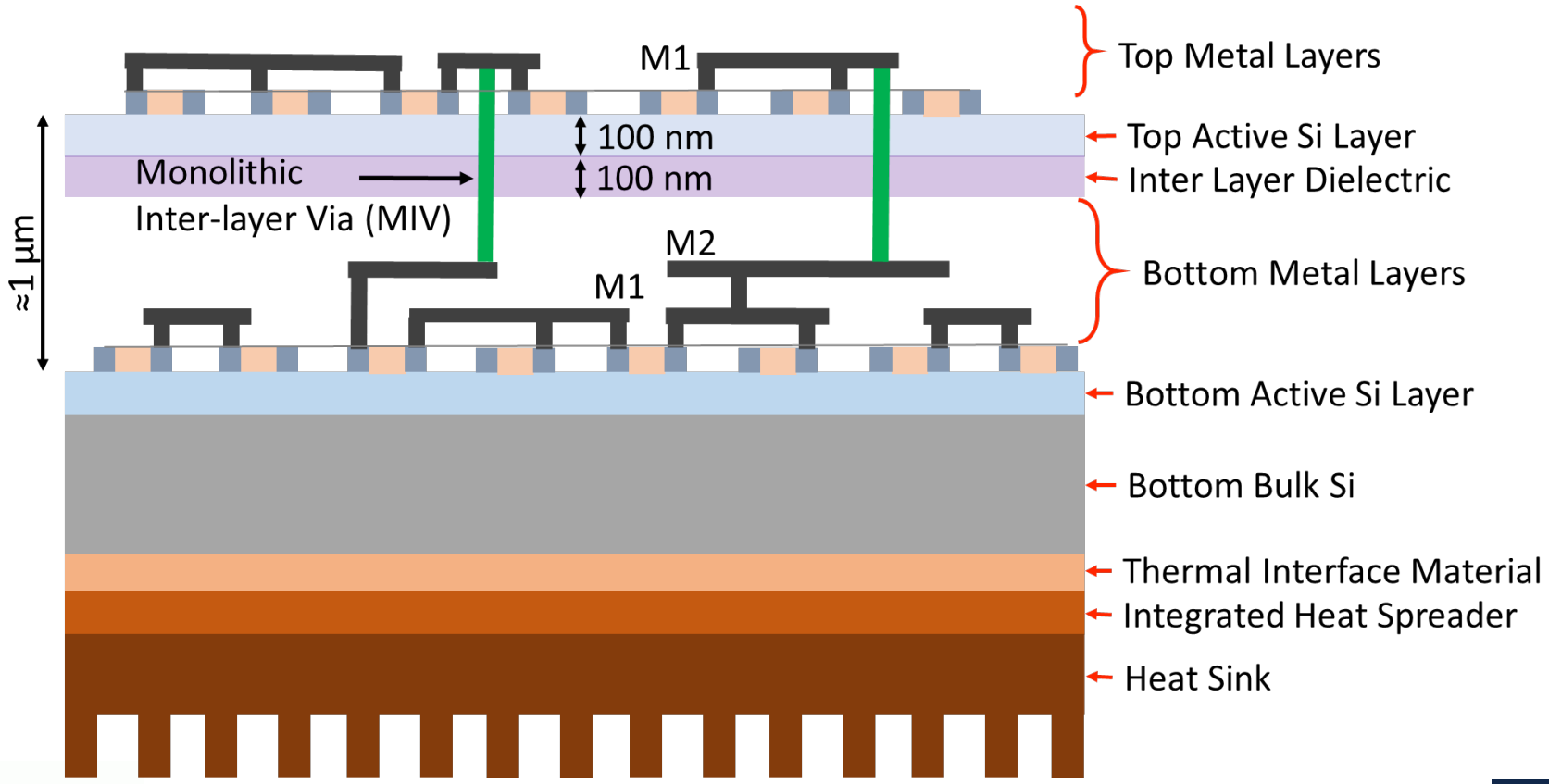
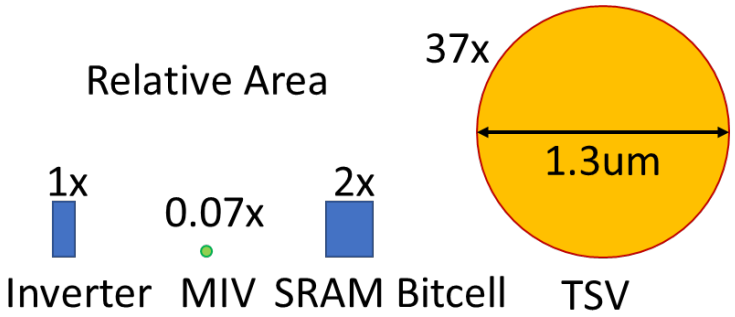


Monolithic 3D vs TSV based 3D Stacking (TSV3D)

- Monolithic Inter-layer Via (MIV) diameter is much smaller
  - Diameter: 50 nm (MIV) vs 1.3 um (TSV)

- Layers are close to each other
  - Better vertical thermal conduction



✓ Fine-grained integration
✓ High bandwidth and low latency
✓ Good vertical thermal conduction

Challenges of Monolithic 3D Integration

- Manufacturing the top layer without compromising the base layer
  - Conventional approach: High temperature steps in top layer fabrication
  - This hurts the bottom layer (metal and active silicon)

- Alternative: Use lower temperature process for the top layer

✓ Doesn't hurt the bottom layer
✗ Performance degradation in top layer

Contribution: Designing Vertical Processors in Monolithic 3D

- Design vertical cores by partitioning the pipeline stages into two layers -- with and without top layer performance degradation
- First, partition the core assuming no slowdown in top layer
- Next, mitigate the impact of the top layer slowdown
  - Critical Path Aware Partitioning for logic and storage stages.
- Our evaluation shows an M3D core can significantly improve performance over a 2D or TSV3D design while reducing energy consumption

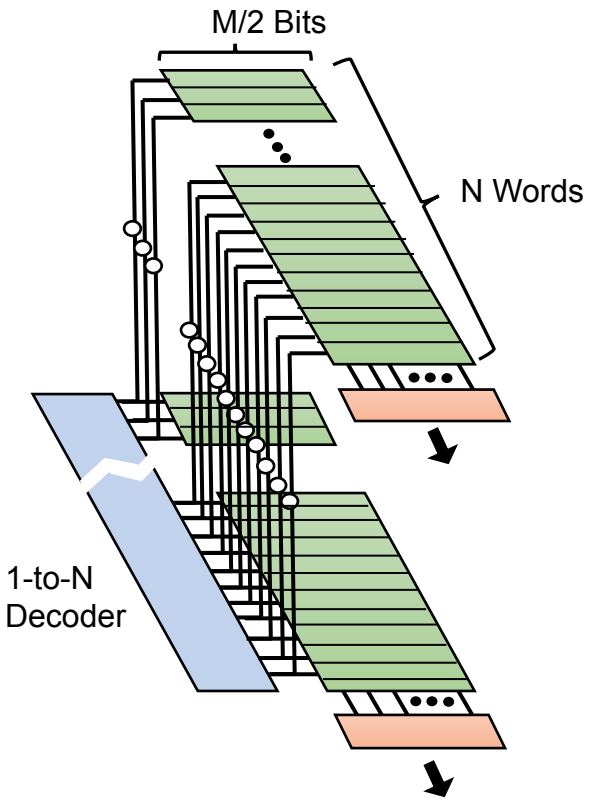
Partitioning Storage Stages in M3D

- SRAM/CAM structures within the core:
  - *Multi-ported*: Register File, Register Alias Table, Issue Queue etc.
  - *Single-ported*: Branch predictors, BTB, L1/L2 etc.

- 3D SRAM/CAM array partitioning schemes [1]
  - Bit Partitioning
  - Word Partitioning
  - Port Partitioning

[1] K. Puttaswamy and G. H. Loh. 2009. 3D-Integrated SRAM Components for High-Performance Microprocessors. IEEE Trans. Comput. (Oct 2009).

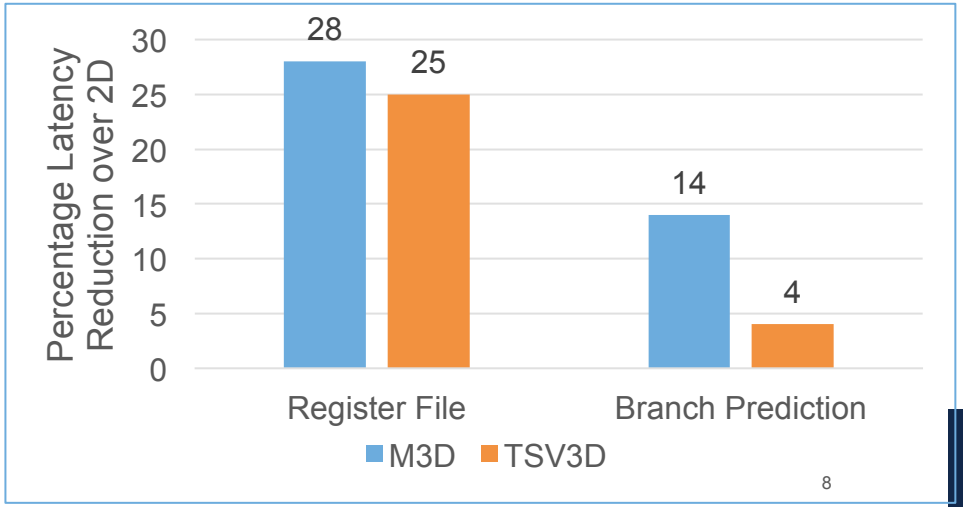
Bit Partitioning



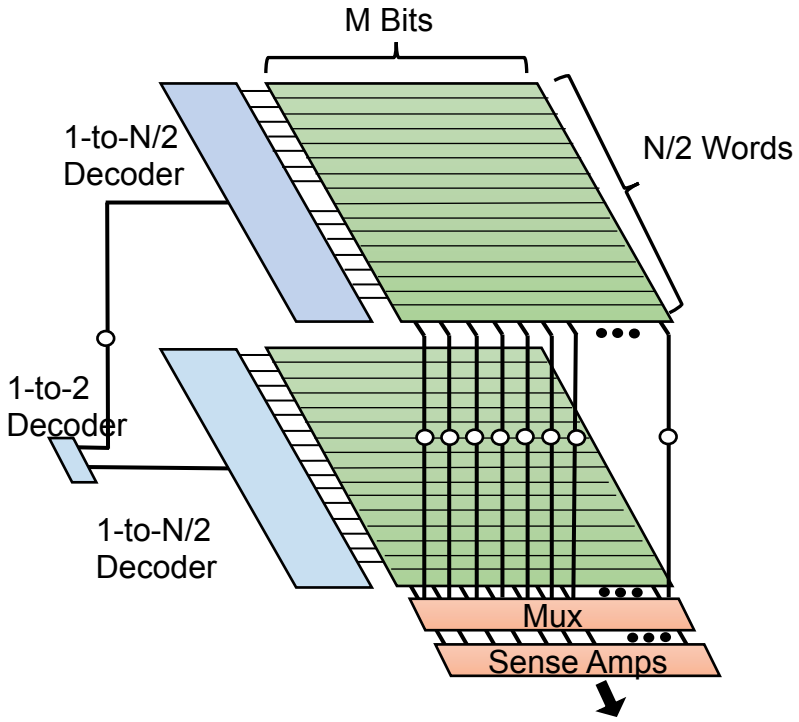
- Distribute half the bits of every word in each layer
- Each word requires an inter-layer via

- Multiported structure (e.g. Register File):
  - Bigger bitcells → higher gains

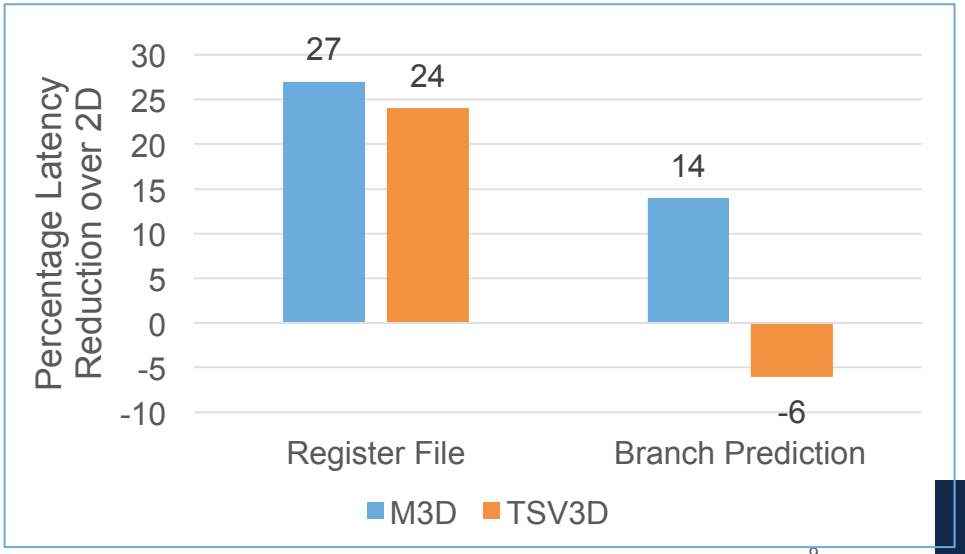
- Singleported structure (e.g. Branch Predictor):
  - Smaller bitcells → lower gains



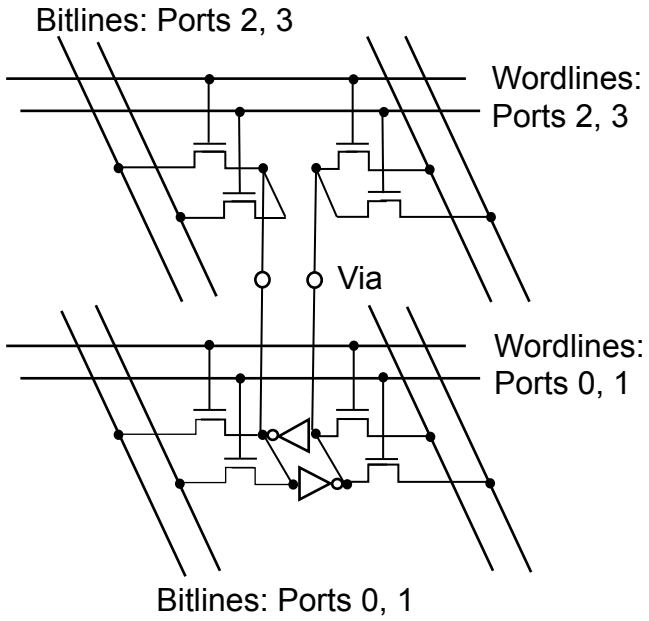
Word Partitioning



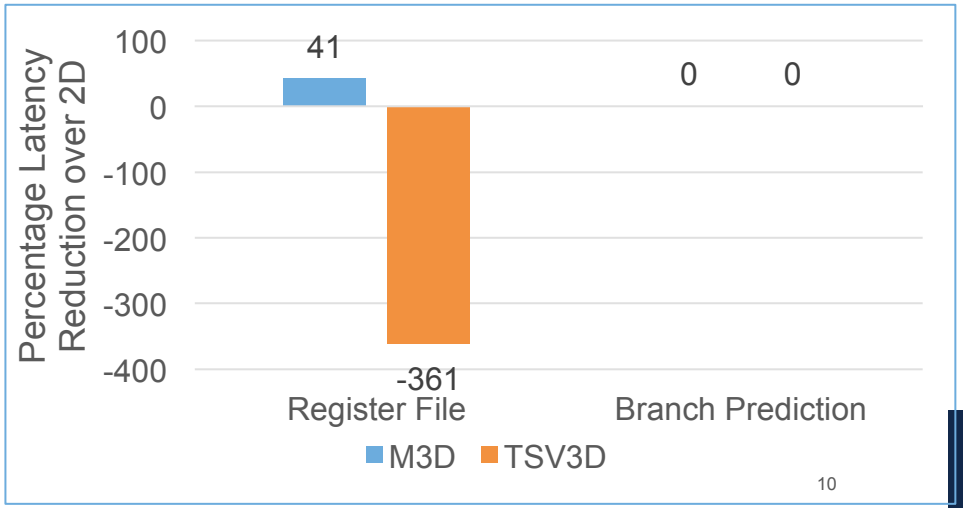
- Distribute half of the words in each layer
- Requires one inter-layer via per bit
- Similar behavior as Bit partitioning



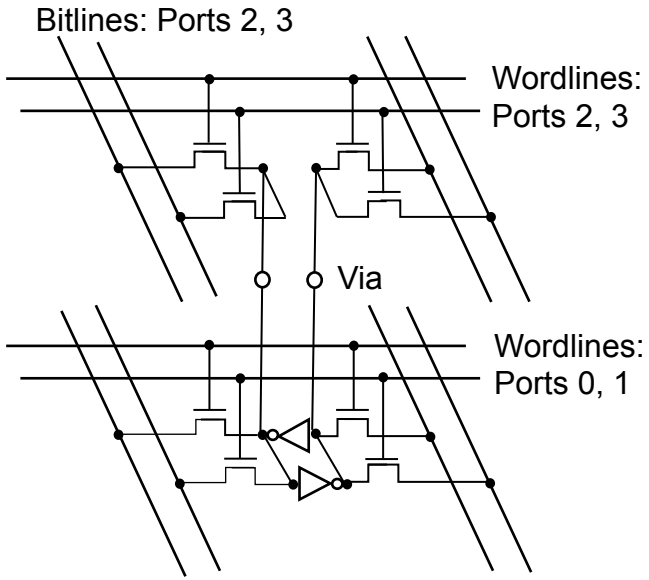
Port Partitioning



- Distribute half the ports in each layer
- Quadratic reduction in area footprint
- Two vias per bitcell
- Applicable only for multiported structures
- TSVs simply have too much area overhead



Port Partitioning



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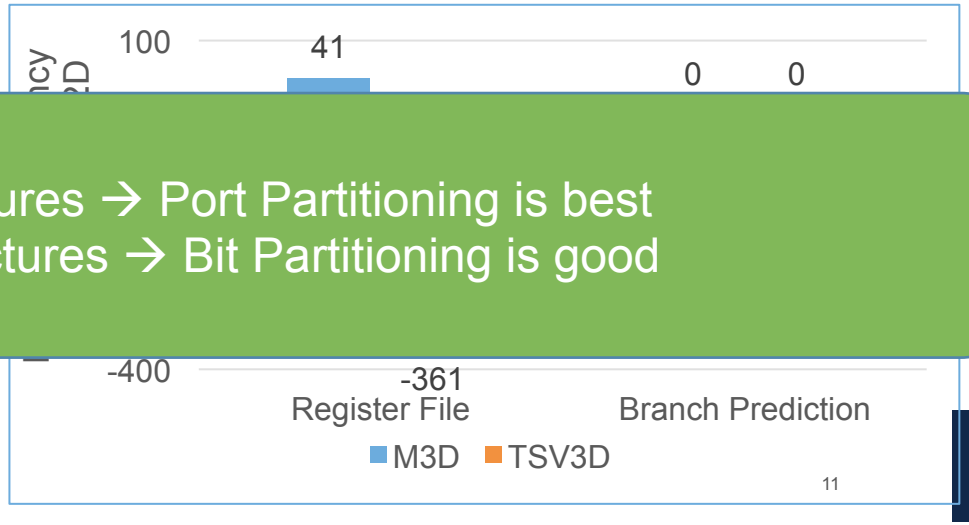


Multiported structures → Port Partitioning is best
Singleported structures → Bit Partitioning is good

Partitioning Logic Stages in M3D

- Benefit: Reduction in wire delay

- Semi-global wires are significantly shorter
  - Critical paths with in a core such as load-to-use, branch misprediction, ALU+Bypass are shorter
  - Improves both core frequency and IPC

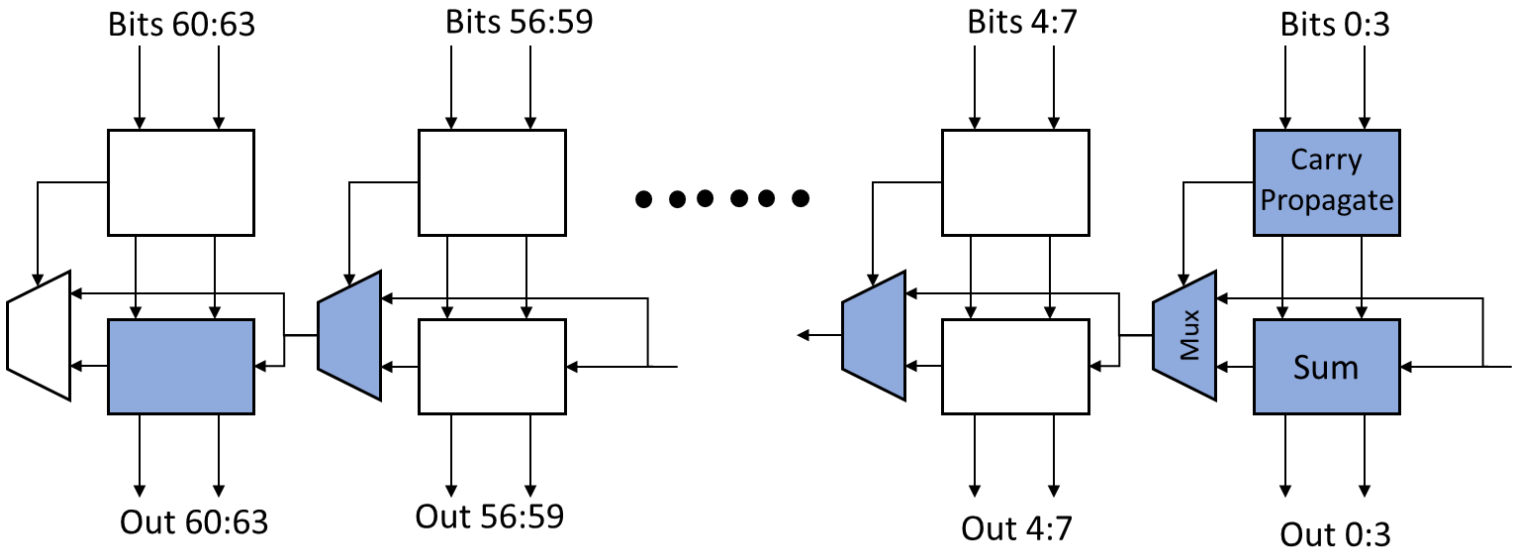
Hetero Layer Partitioning (M3D-Hetero)

- Low temperature processing → performance degradation in the top layer
  - Top layer inverter delay: 17% lower
  - Overall frequency: 9% lower

- Propose: Mitigate the impact through Critical Path Aware Partitioning

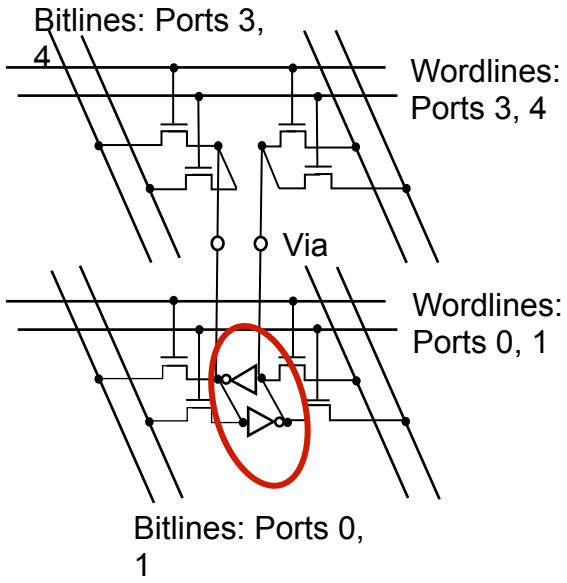
M3D-Hetero Logic Stages: Execution Unit

- ALU has many paths that are not critical to stage delay
  - For example, in a carry skip adder, only shaded parts are critical.
  - Propose: Place the critical paths in bottom layer ; rest in the top layer



M3D-Hetero Storage Structures

- Port Partitioned Structures:
  - Area slack exists in top layer, as the bitcell is only in the bottom layer
  - Propose: *Asymmetric Port Partitioning*
    - Increase the size of access transistors in the top layer (for speed)
    - Place more ports in bottom layer than in top layer



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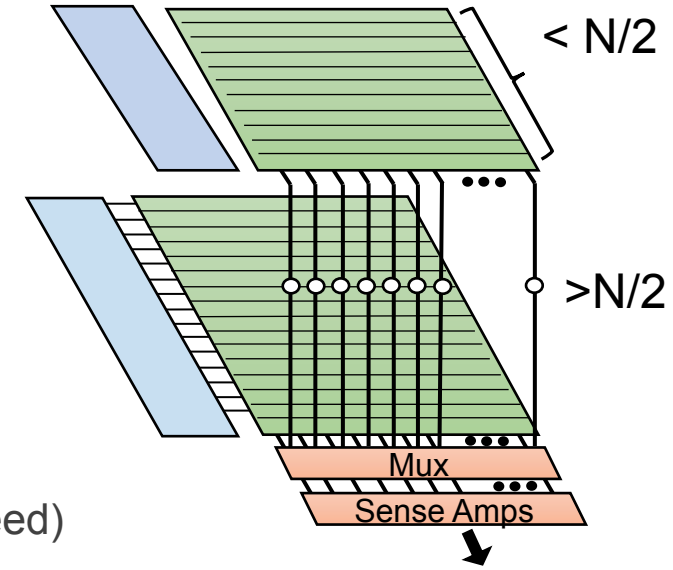
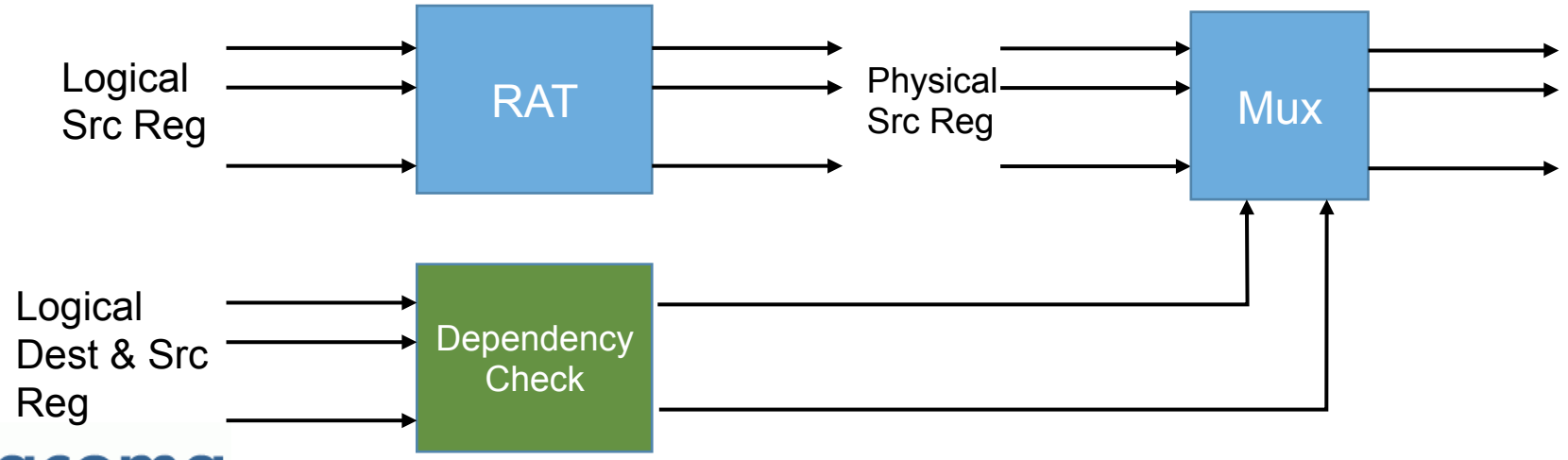


- Bit/Word Partitioned Structures:
  - Propose: *Asymmetric Array Partitioning*
    - Asymmetrically partition bits/words across layers
    - Assign smaller section to the top layer
    - Increase the size of transistors in top layer (for speed)

M3D-Hetero Stages with both Logic and SRAM Structures

- Rename consists of Register Alias Table (RAT) and other logic:
  - Register Alias Table (multi-ported) → Perform asymmetric port partitioning
  - Dependency check → Place in top layer (Not critical)
  - Shadow RAT tables → Place in top layer (Not critical)
  - Decoder to RAT and peripheral logic → Place in bottom layer (Critical)



Summary: Hetero Layer Partitioning in M3D

Stage Type	Mitigation Technique	
Logic Stages	Critical paths in bottom layer; non-critical paths in top	
Storage Stages	Port Partitioning	Asymmetric partitioning of ports; and larger access transistors in top layer
	Bit/Word Partitioning	Asymmetric partitioning of array; and larger bitcells in top layer
Mixed Stages	Combination of above techniques	

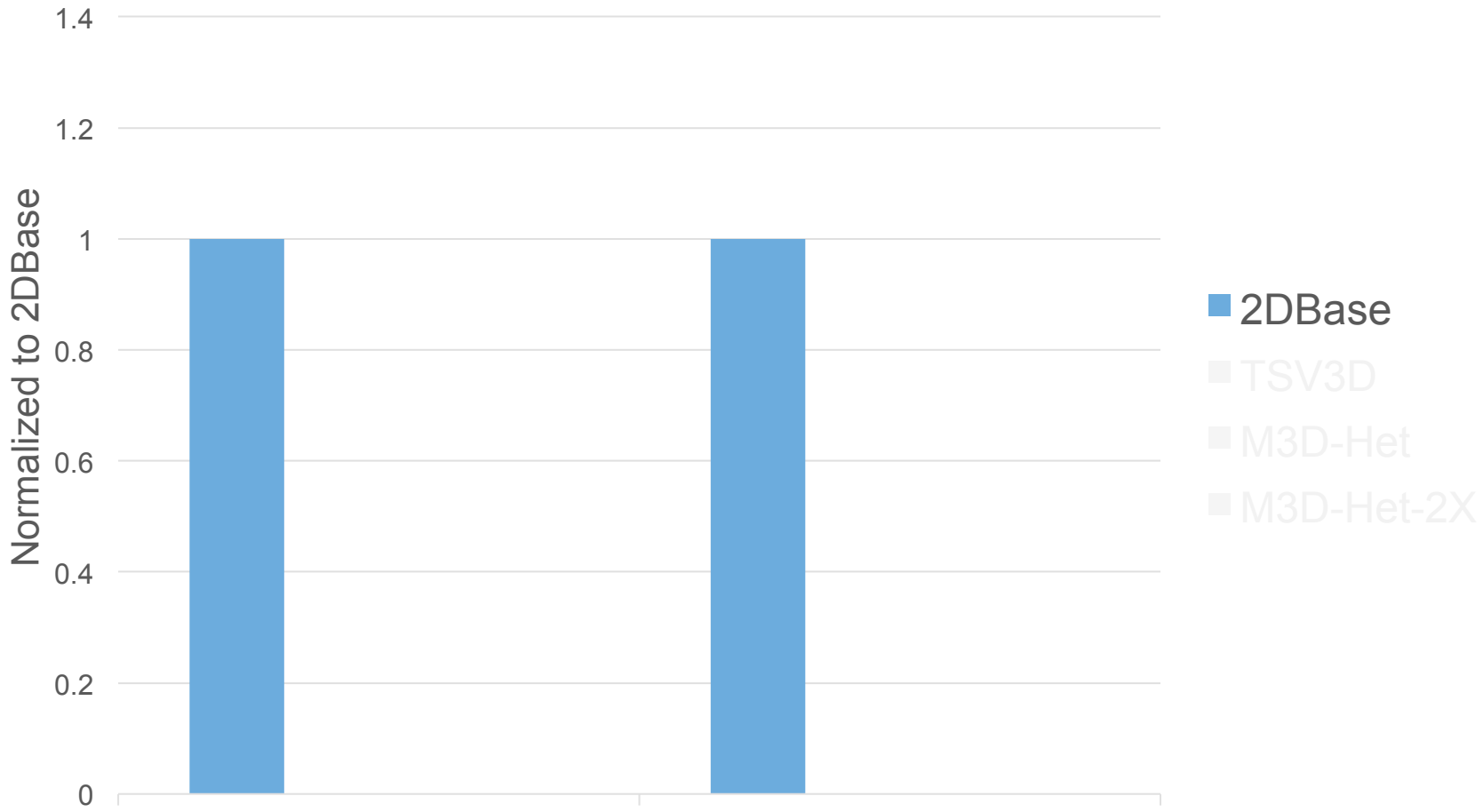
How to Exploit Stage Delay Reduction in M3D ?

- ✓ Increase frequency
- ✓ Increase the size or the number of ports for key structures
  - Register File, Issue Queue etc.
  - Increase issue width at same frequency
- ✓ Keep the same frequency, but reduce the voltage
  - Operate more cores within the same power budget

Evaluation: Configurations & Frequency

- *2D Base:* Four 6-wide OOO cores
  - Caches: DL1 & IL1 32KB ; L2 256 KB ; Entries: RF(160) ; ROB(192) ; IQ(84) ; LQ(72); SQ(56)
  - Frequency = 3.3 GHz
- *M3D-Het* : M3D with top layer slowdown and our modifications
  - Stage with lowest delay reduction: SQ/BPT at 13%
  - Frequency = 3.79 GHz
- *TSV3D:* Traditional TSV3D
  - Stage with lowest delay reduction: BTB at -6% (negative)
  - Frequency = 3.3 GHz
- *M3D-Het-2X:* Increase cores within same power budget
  - 2X as many cores at F = 3.3 GHz

Evaluation of M3D Design Choices



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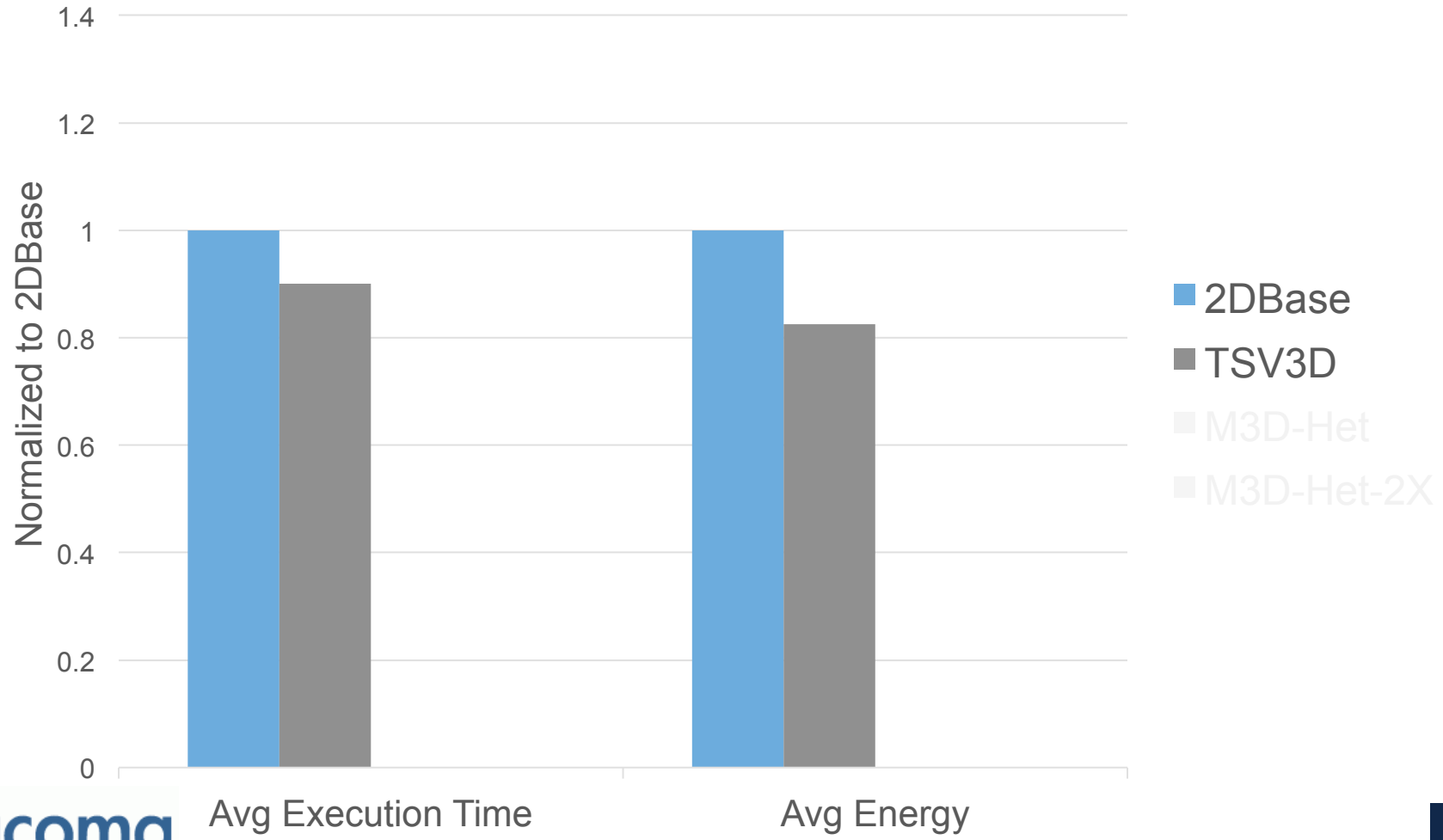

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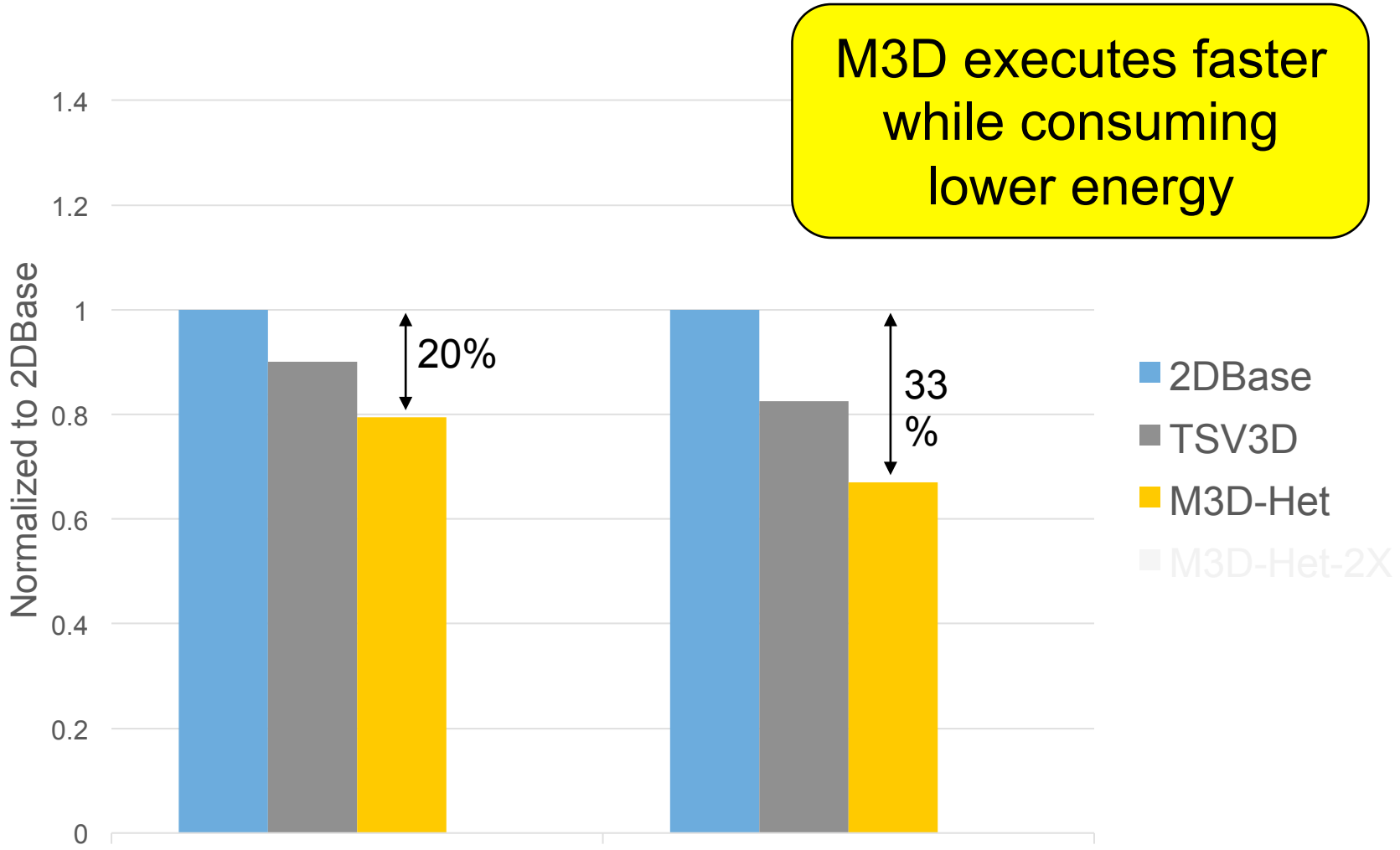
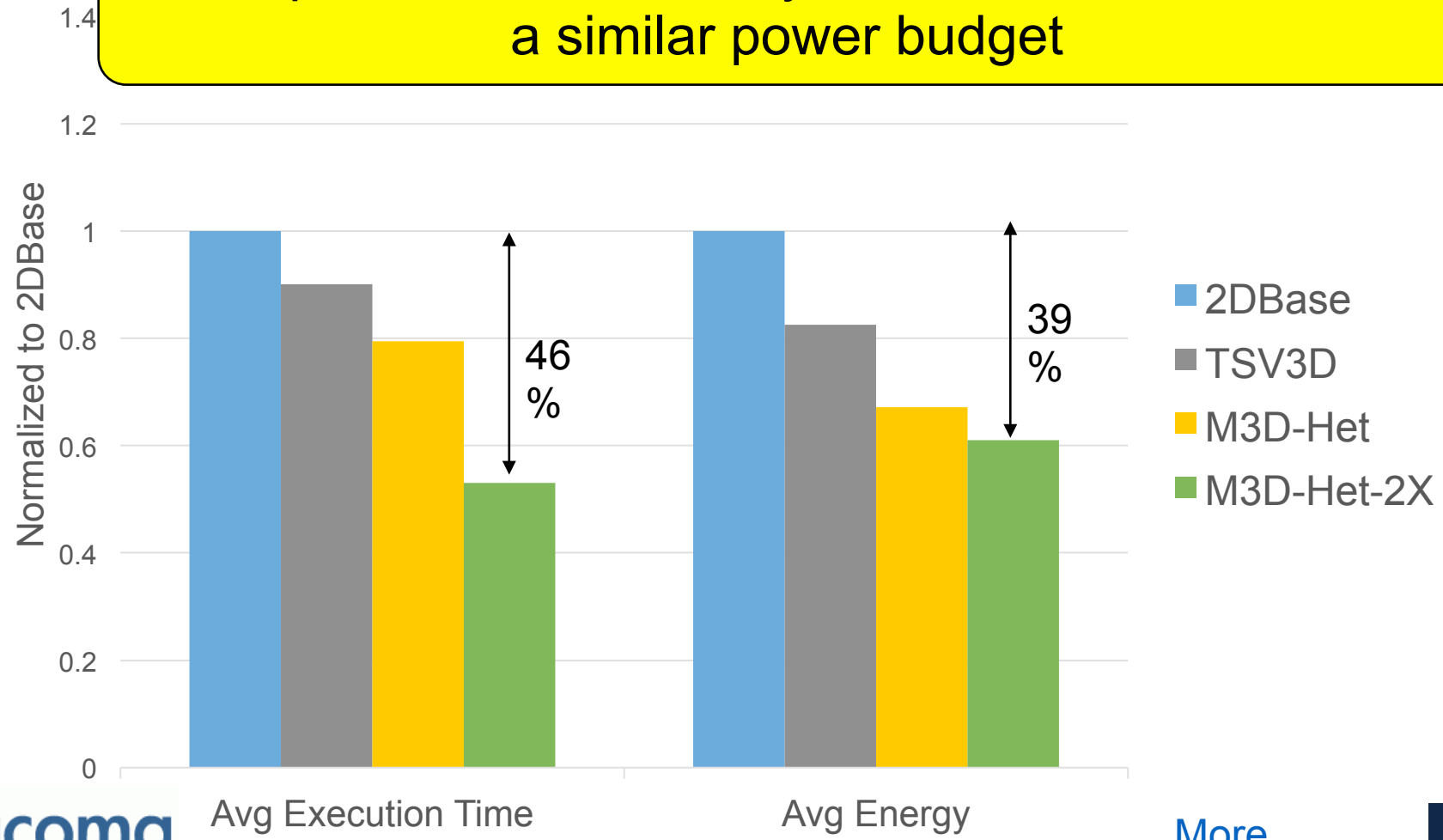


Evaluation of M3D Design Choices

Can operate twice as many M3D cores as 2DBase in a similar power budget



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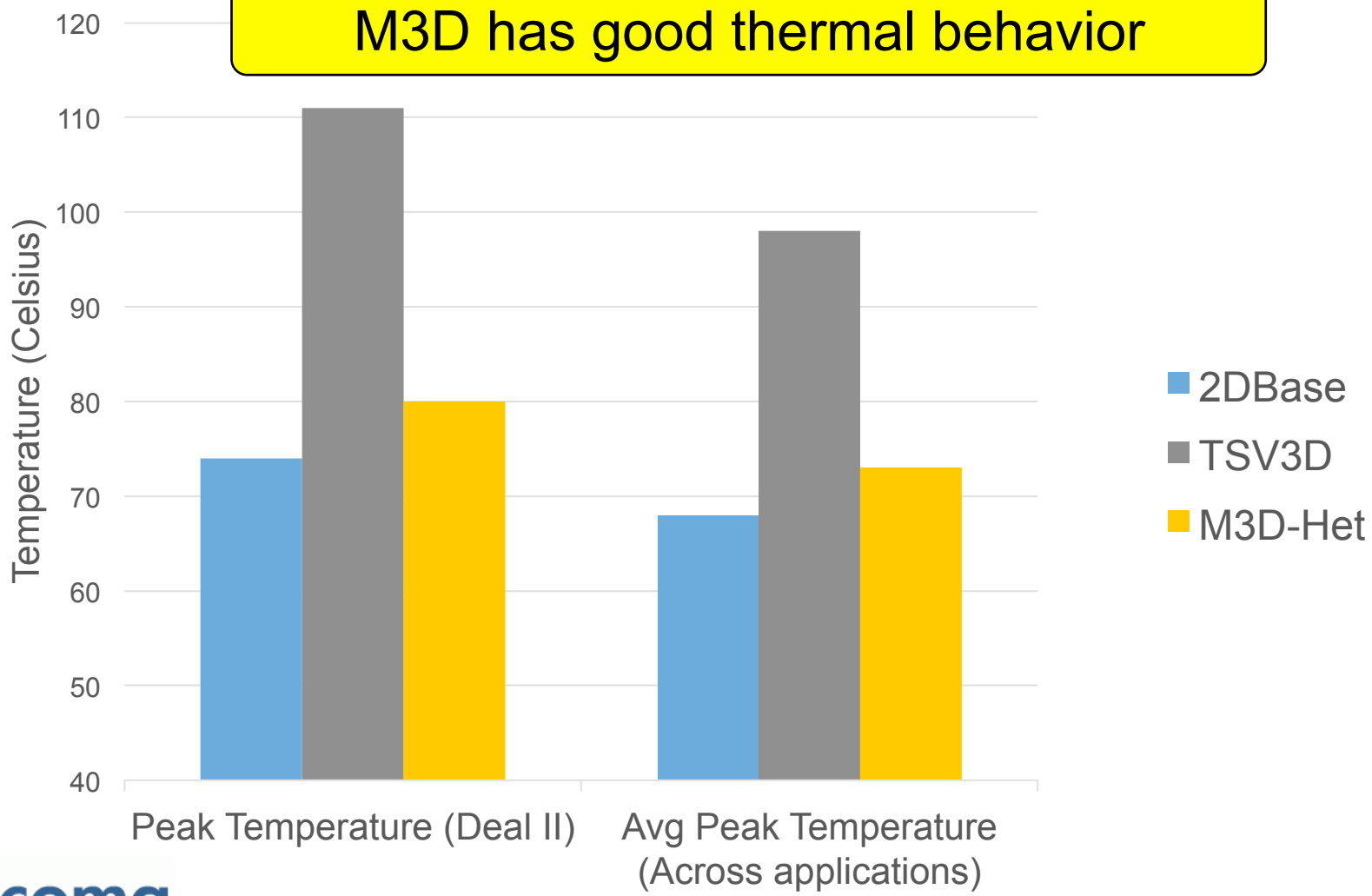
More Results [24]

Thermal Behavior: Peak Temperature

M3D has good thermal behavior



Summary: Designing Vertical Processors in Monolithic 3D

- First work to partition a core in an M3D stack
- Proposed Critical Path Aware Partitioning strategies to mitigate the performance impact of a degraded top layer.
- Overall, M3D can operate twice as many cores as a 2D design within a similar power budget
  - Improves execution time by 46% while consuming 39% lower energy.

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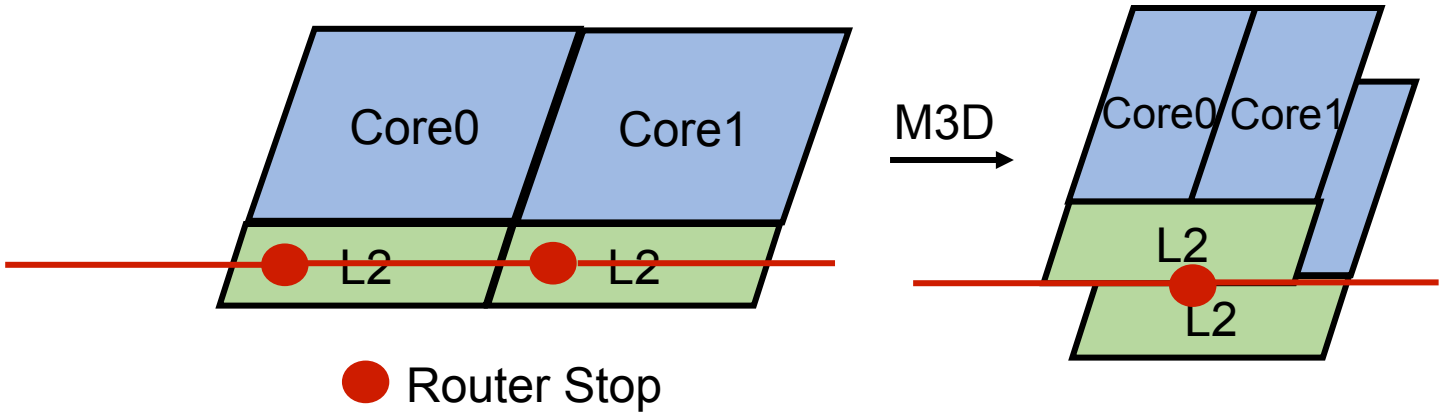
Backup

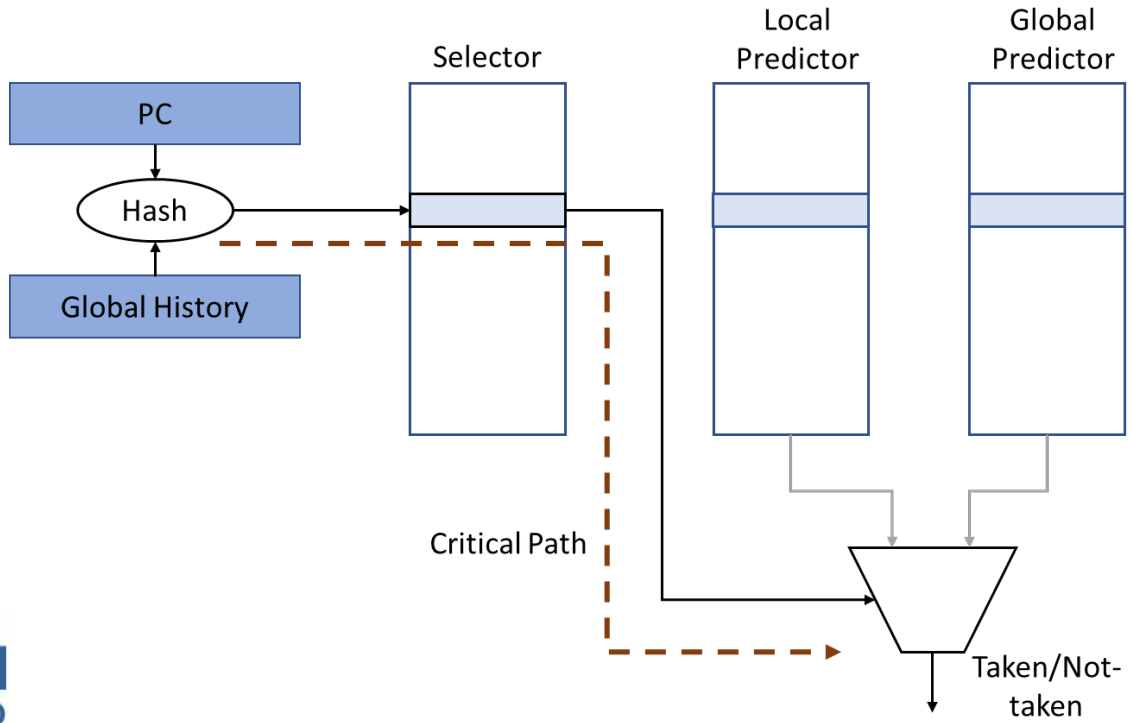
Caches and NoC

- Shared L2 Cache, and NoC Router Stop across two adjacent cores



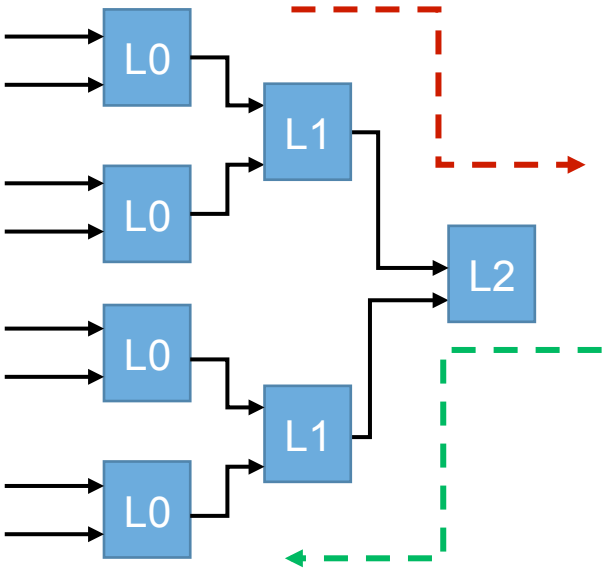
Stages with Logic and SRAM Structures

- Fetch and Branch Prediction:
  - Consists of 4 parallel paths: Increment PC, RAS, BTB and Branch Prediction
  - RAS, increment PC are non-critical and are in top tier
  - BTB access and Branch Prediction are both critical and use asymmetric array partition



Stages with Logic and CAM Structures

- Issue Stage consists of Wakeup and Select logic:
  - Wakeup consists of IQ which is a CAM structure → Asymmetric port partitioning
  - Select consists of multi-level arbitration
  - Within each arbiter:
    - First phase: Request → critical and is in bottom layer
    - Second phase: Grant → has slack and is in top layer.



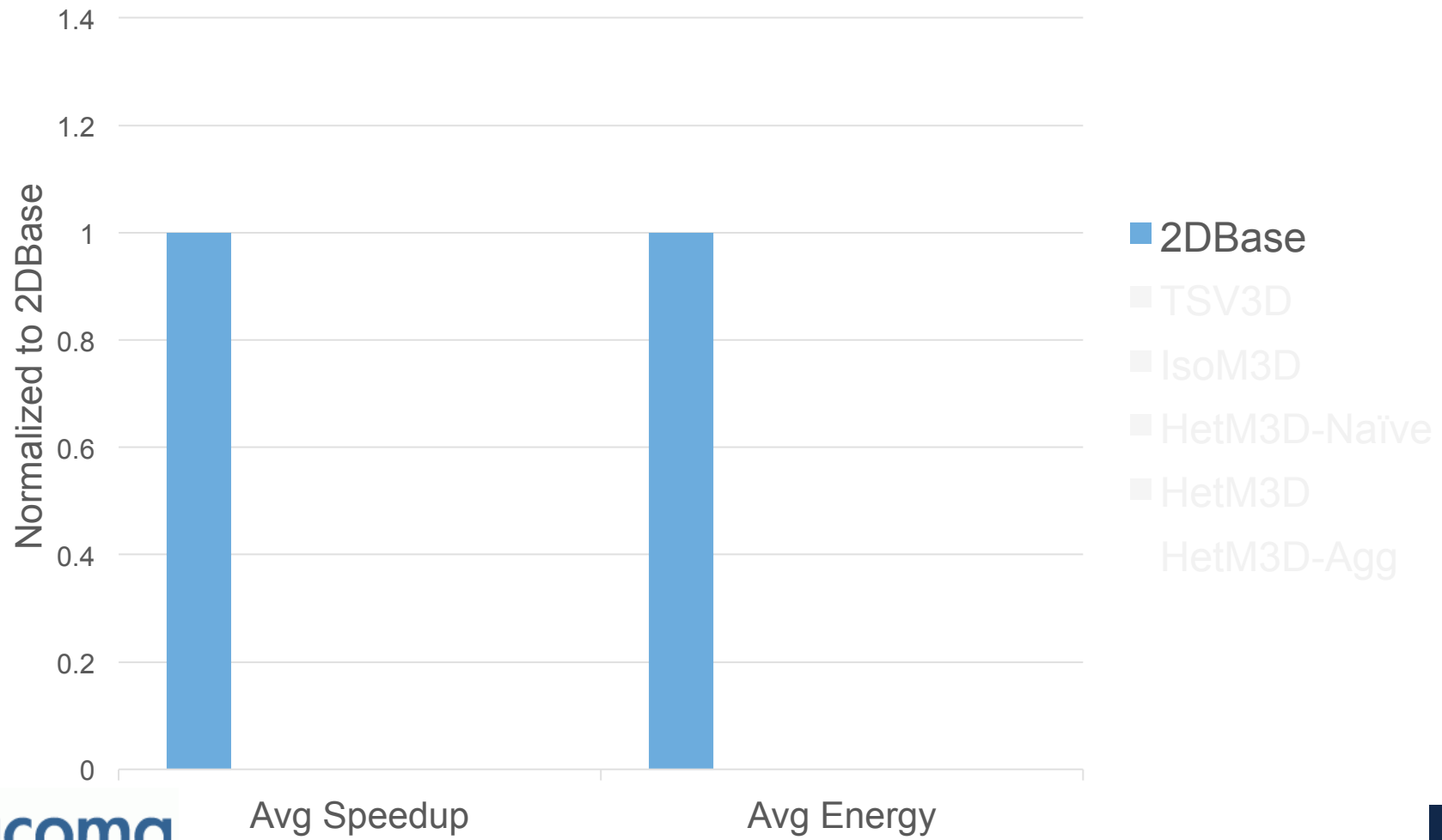
Stages with Logic and CAM Structures

- Load Store Unit:
  - Critical path: Store forwarding to a younger load, on a hit in Store Queue
    - Includes SQ access, Priority encoder and Store buffer access
  - LQ, SQ CAMs → Asymmetric Port partitioning
  - Priority encoder after SQ is placed in bottom layer.
  - Balance area between LQ/SQ across layers.

Evaluation: Frequency of Operation for M3D

- *2D Base*: 6-wide OOO core
  - F = 3.3 GHz
- *IsoM3D:* M3D without top layer degradation:
  - Stage with least delay reduction: SQ/BPT at 14% → F = 3.83 GHz
- *HetM3D–Naïve* : 9% lower frequency due to slow top layer
  - F = 3.5 GHz
- *HetM3D :* M3D with top layer slowdown and our modifications
  - Stage with least delay reduction: SQ/BPT at 13% → F = 3.76 GHz
- *HetM3D-Agg*: An aggressive HetM3D with traditional frequency critical structures
  - IQ (24%) and ALU+Bypass (28%) are the only limiters → F = 4.34 GHz

Single Thread Results: SPEC Benchmark Suite



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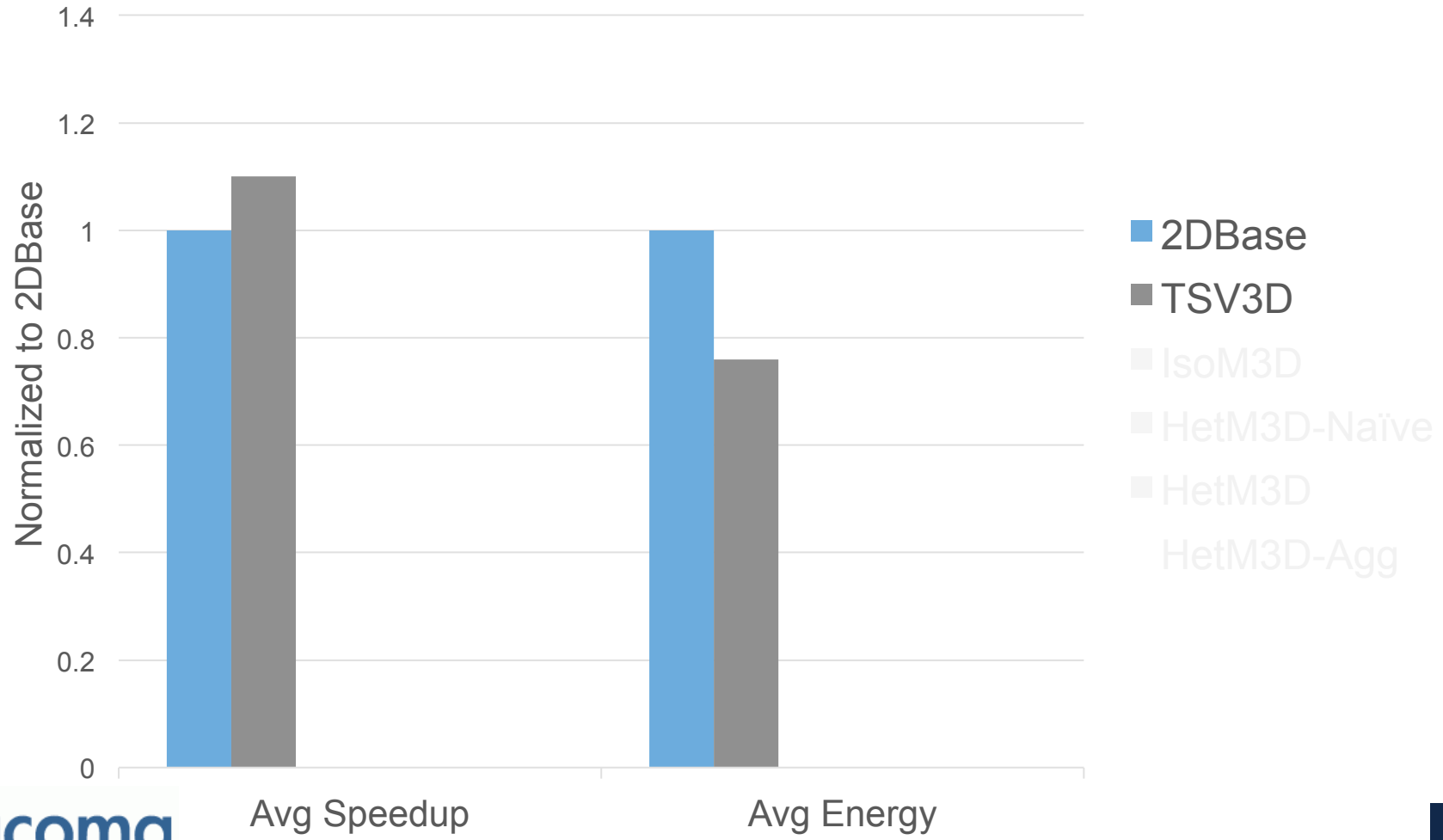

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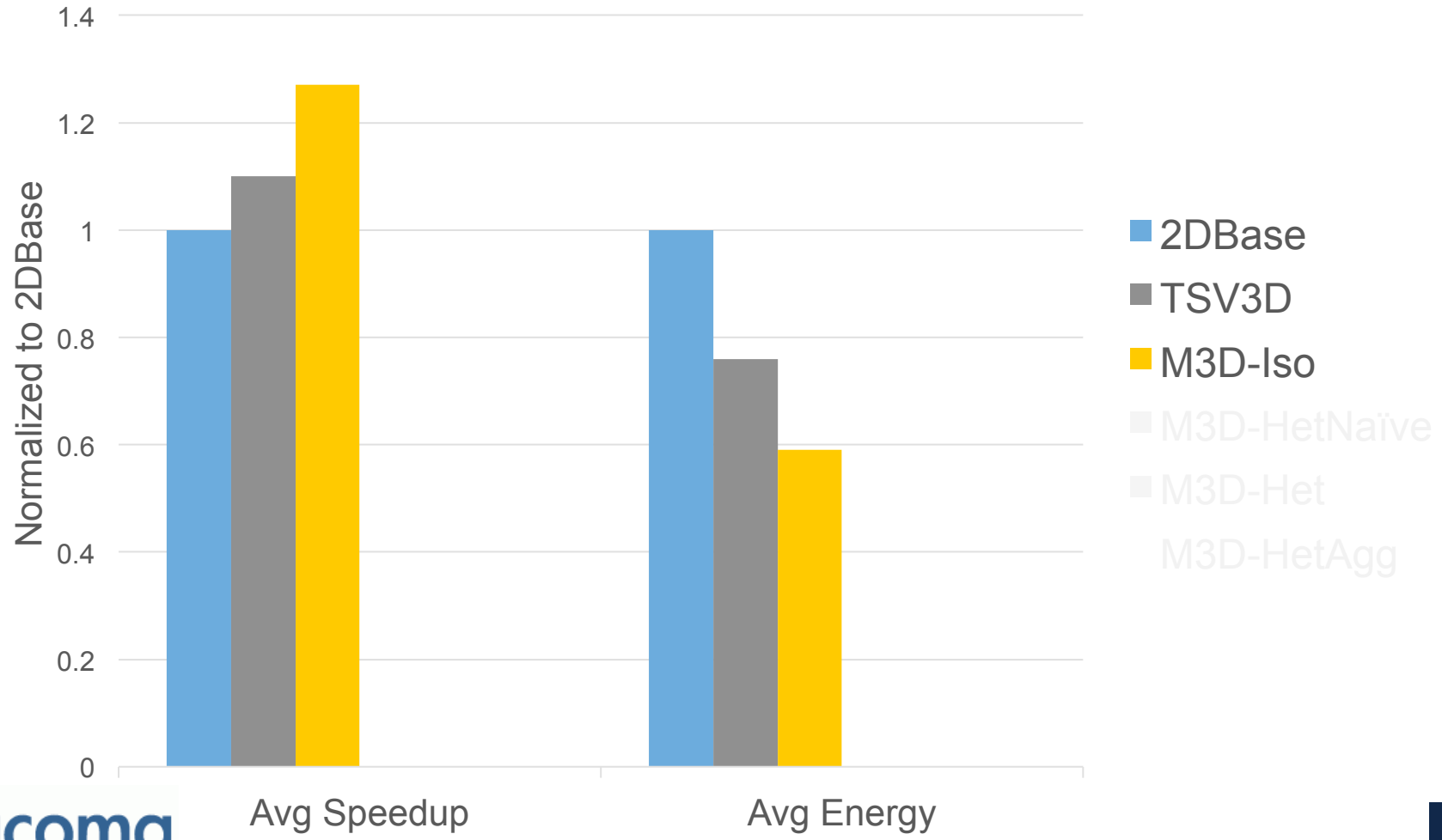

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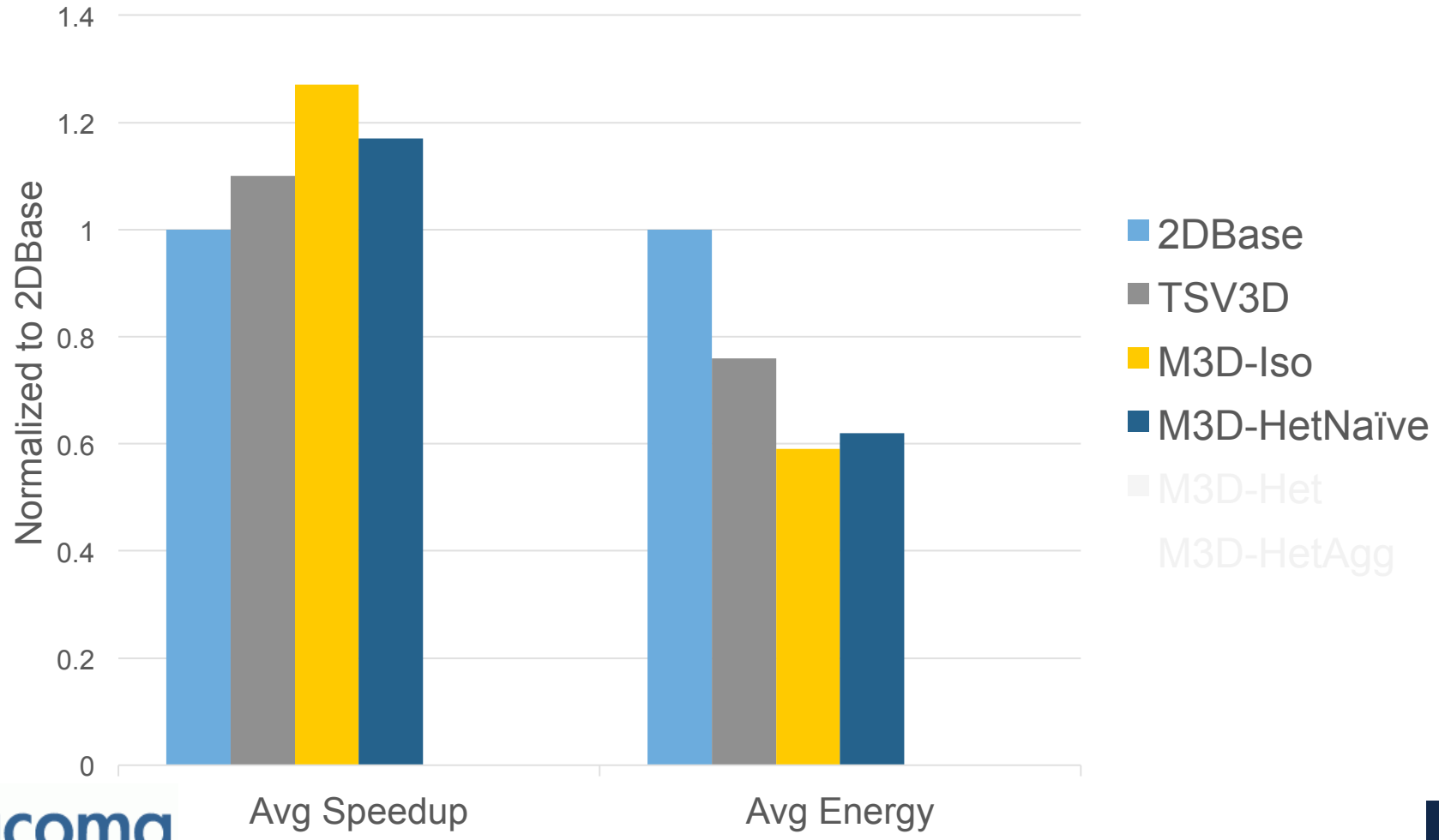

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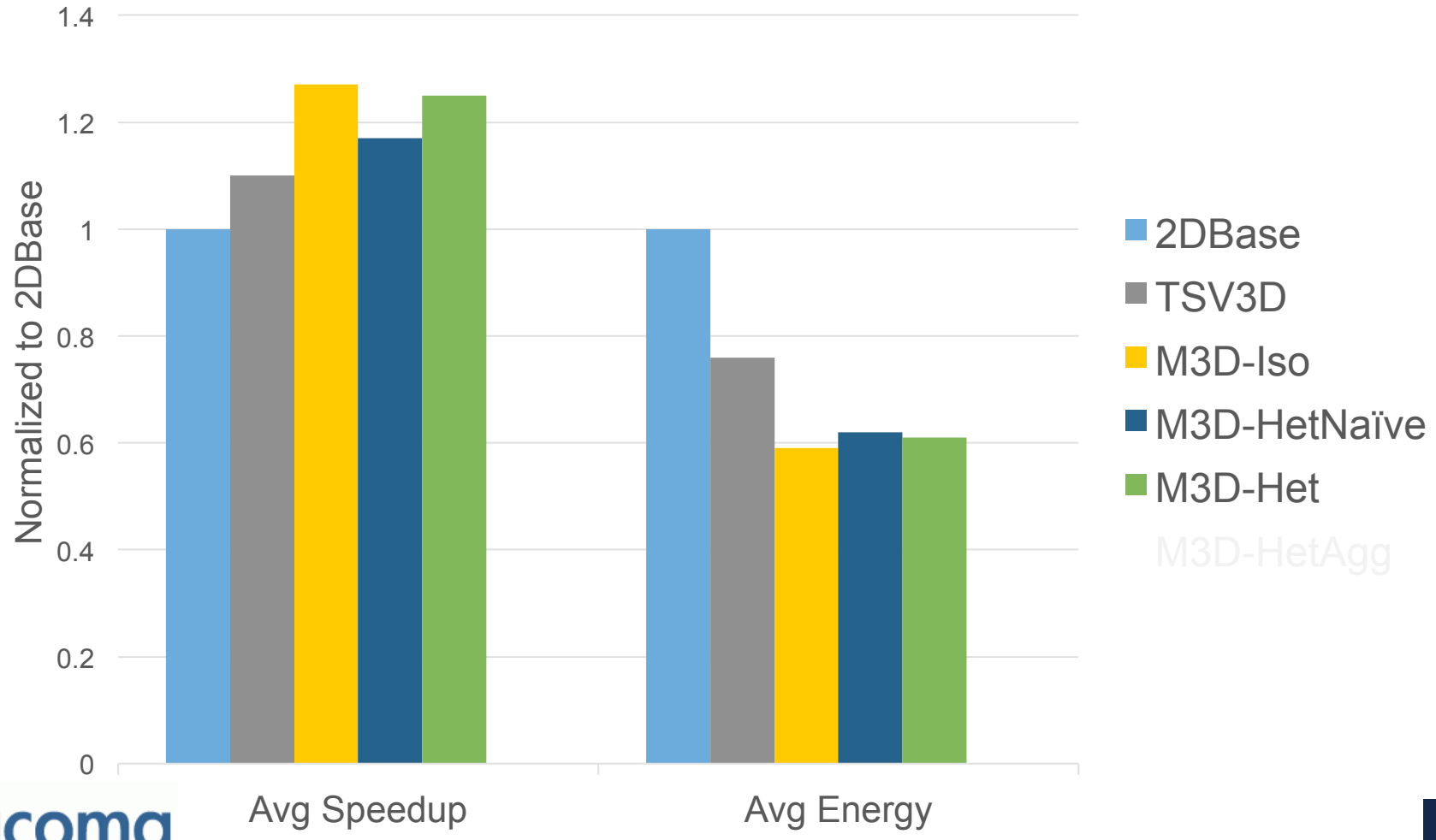

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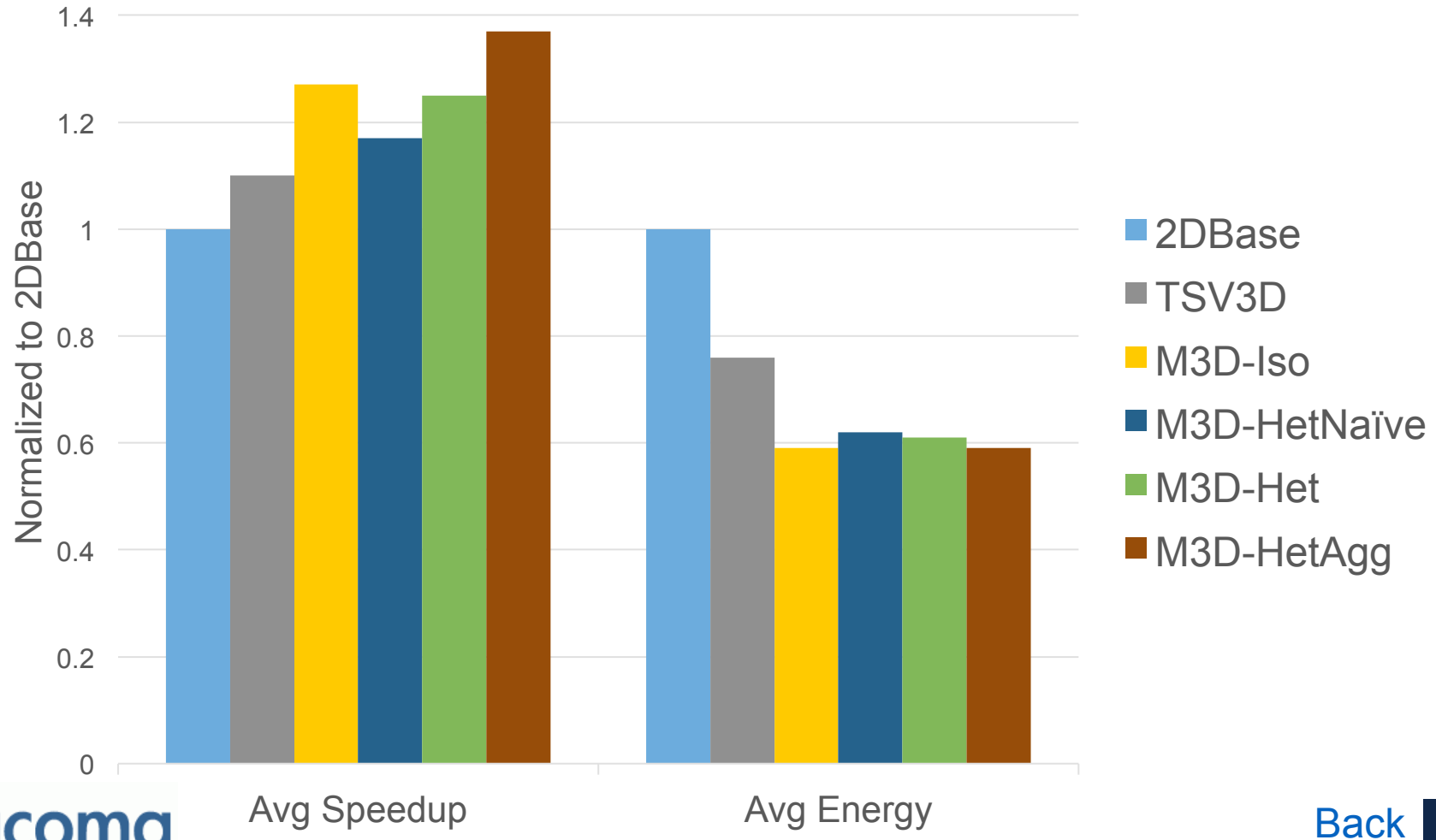

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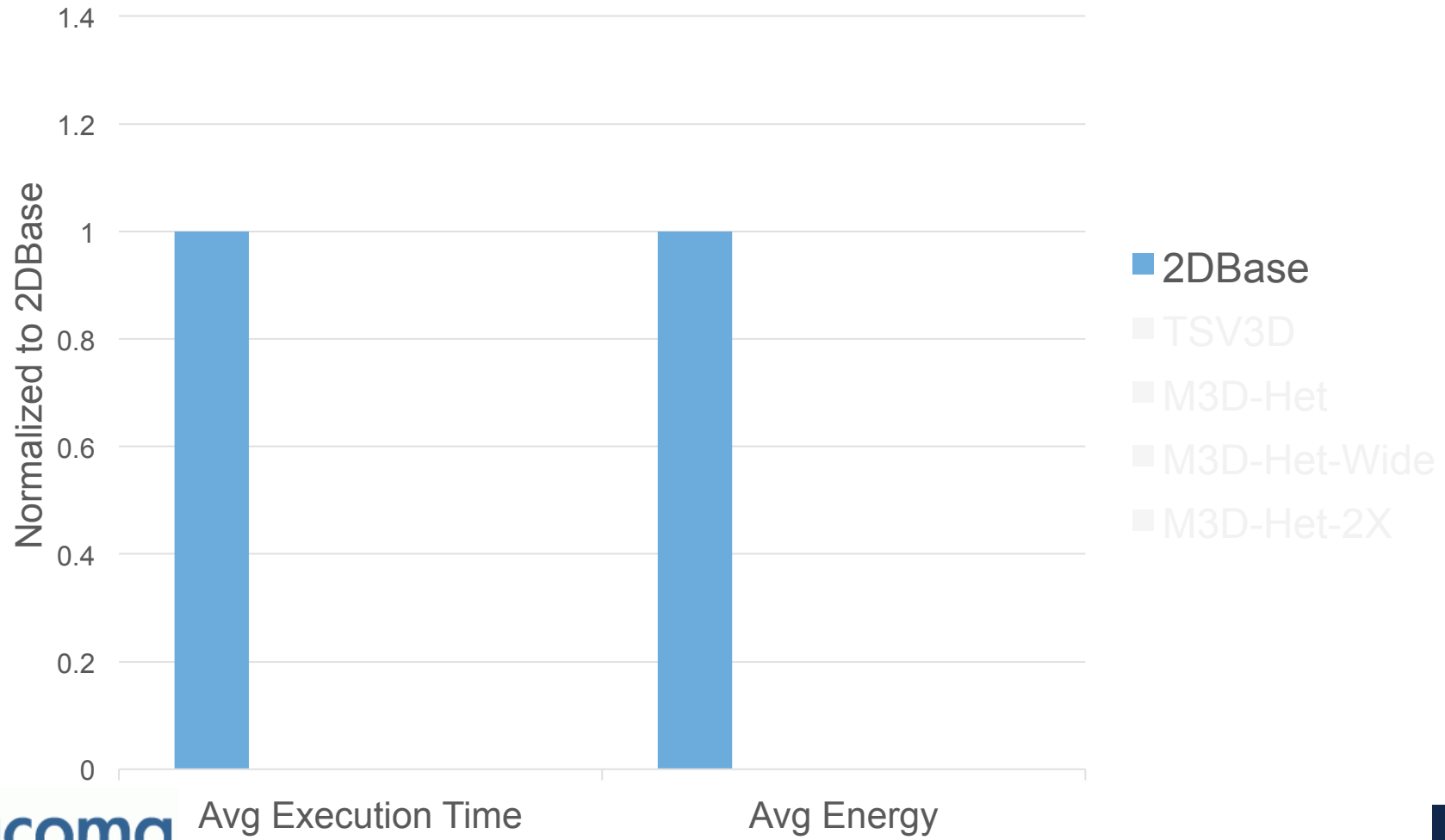

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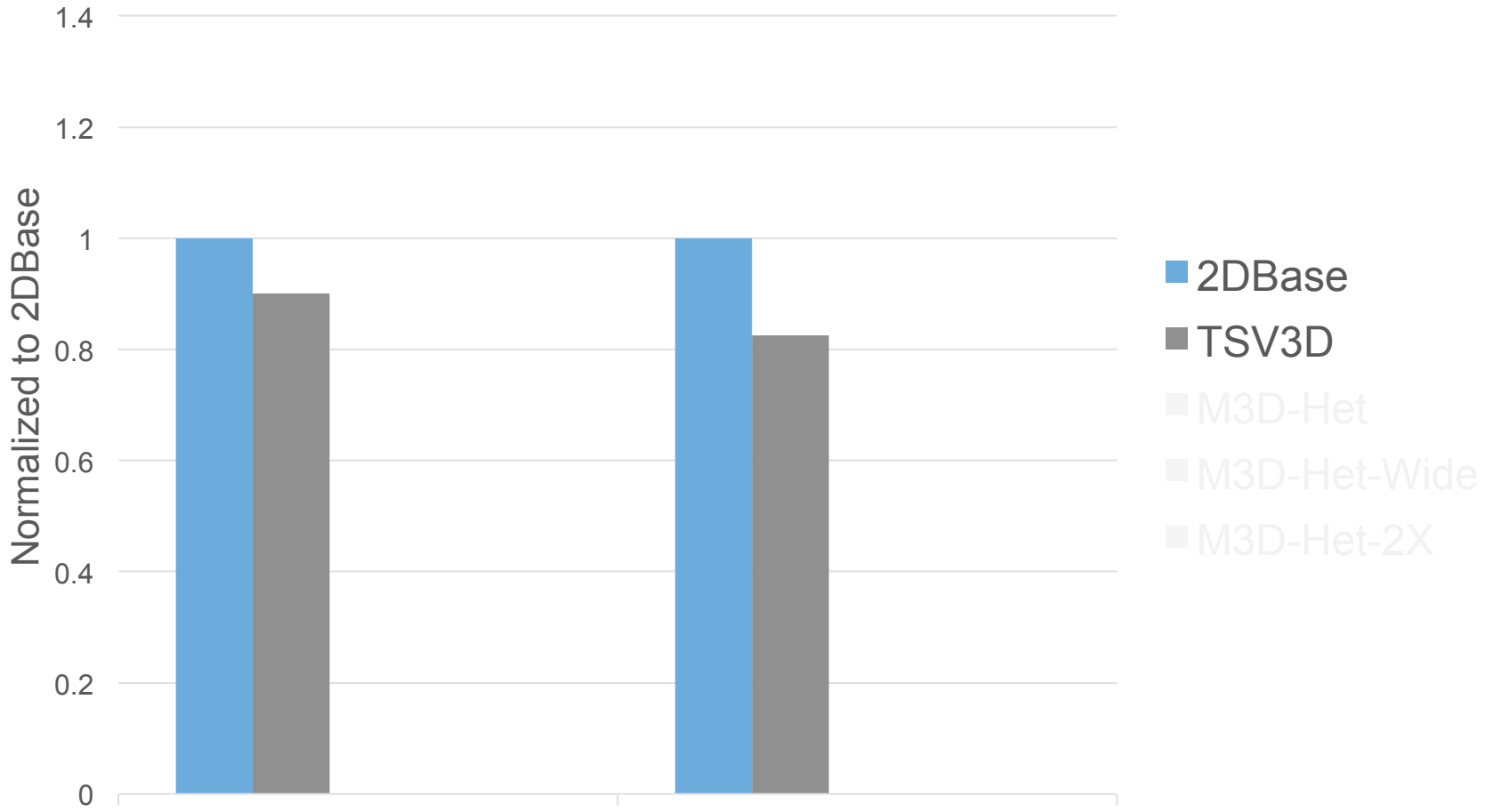

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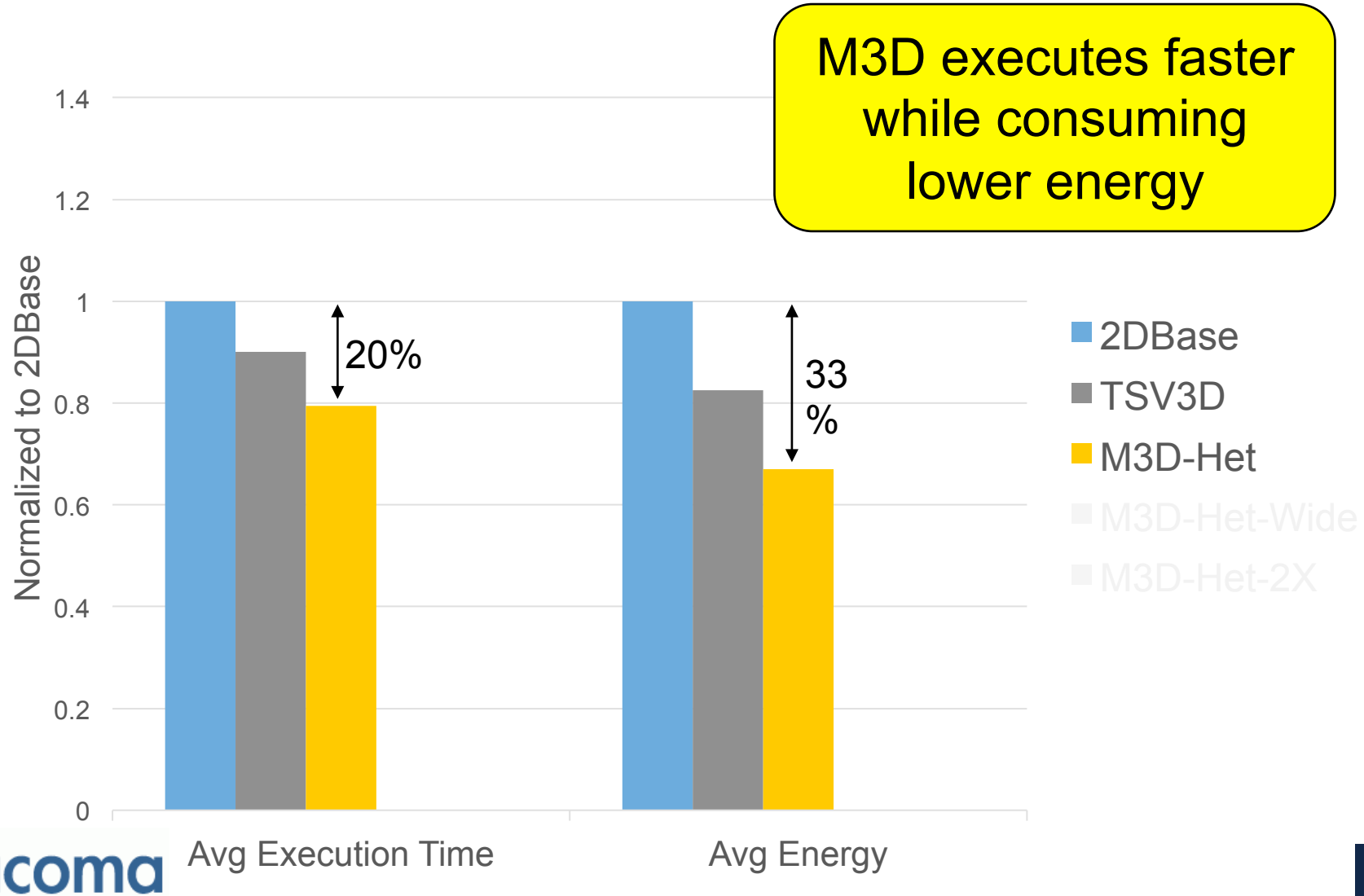

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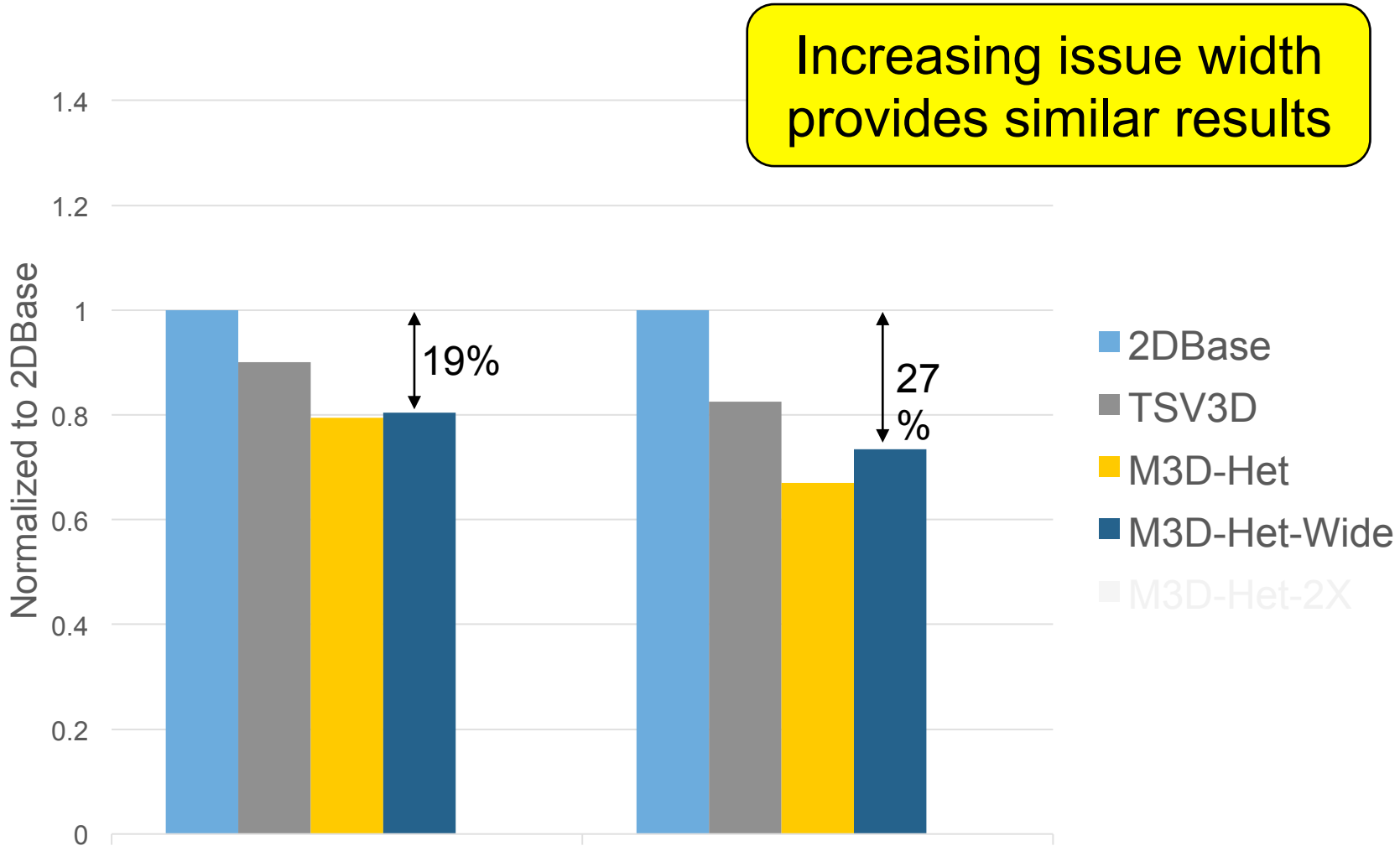

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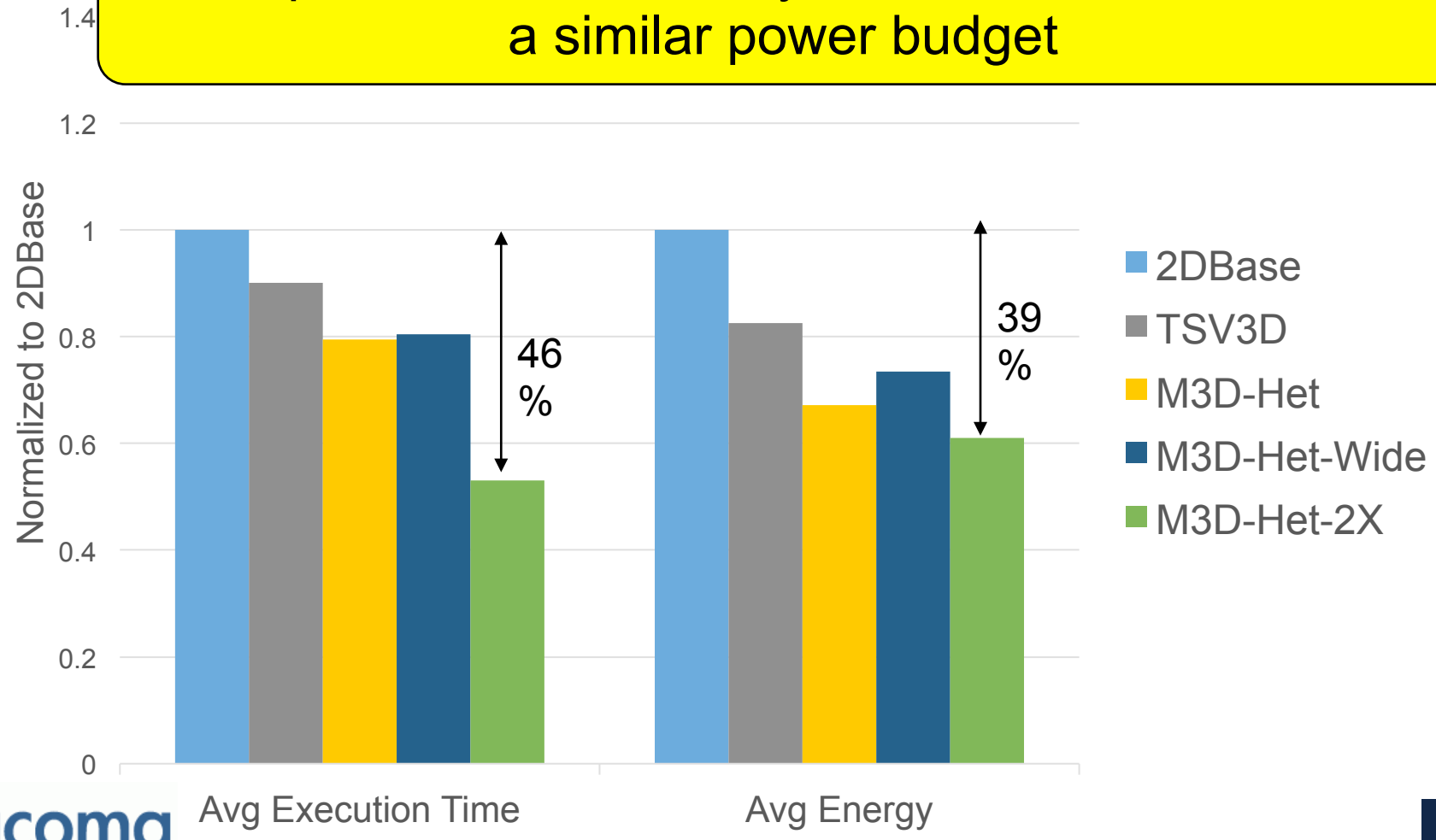


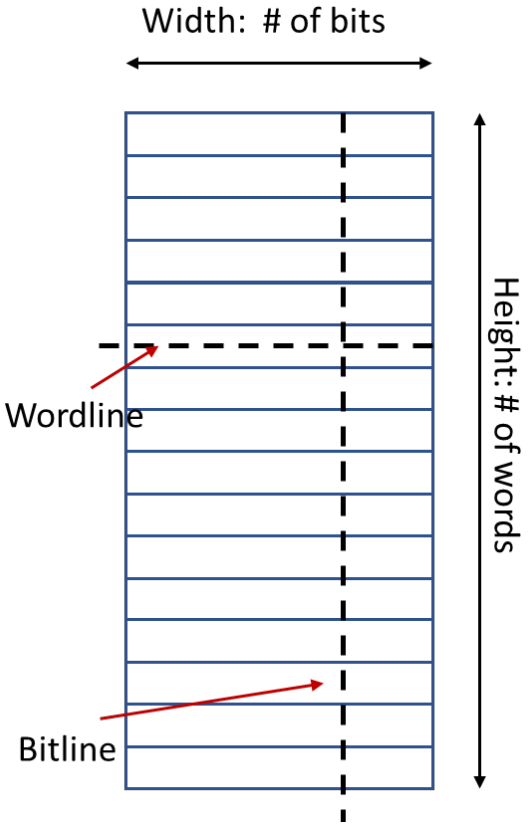
Monolithic 3D Core -- Partitioning Storage Stages

- Storage structures i.e. SRAM/CAM delays are proportional to height and width of an array

$$Width = N_{bits} * (BitcellWidth + K * (N_r + N_w))$$

$$Height = N_{words} * (BitcellHeight + K * (N_r + N_w))$$

$$Area = Width * Height \propto (N_r + N_w)^2$$



Area of multiported cell is quadratic on the number of ports